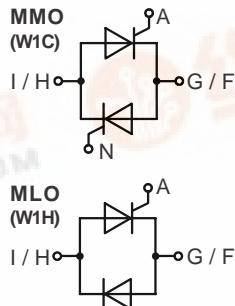


AC Controller Modules

Preliminary Data

V_{RSM}	V_{RRM}	Type
V_{DSM}	V_{DRM}	
V	V	
800	800	MMO 110-08io7
1200	1200	MMO 110-12io7
1400	1400	MMO 110-14io7
		MLO 110-08io7
		MLO 110-12io7
		MLO 110-14io7



Symbol	Conditions	Maximum Ratings	
I_{RMS}	$T_c = 85^\circ\text{C}$, 50 - 400 Hz, module	112	A
I_{TRMS}		81	A
I_{TAVM}	$T_c = 85^\circ\text{C}$; (180° sine)	51	A
I_{TSM}	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine	1000 1070
	$T_{VJ} = 125^\circ\text{C}$ $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine	870 930
I^2t	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine	5000 4810
	$T_{VJ} = 125^\circ\text{C}$ $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine	3780 3630
$(di/dt)_{cr}$	$T_{VJ} = 125^\circ\text{C}$ $f = 50 \text{ Hz}$, $t_p = 200 \mu\text{s}$ $V_D = \frac{2}{3} V_{DRM}$ $I_G = 0.45 \text{ A}$ $di_G/dt = 0.45 \text{ A}/\mu\text{s}$	repetitive, $I_T = 50 \text{ A}$ non repetitive, $I_T = I_{TAVM}$	100 500
$(dv/dt)_{cr}$	$T_{VJ} = 125^\circ\text{C}$; $V_{DRM} = \frac{2}{3} V_{DRM}$ $R_{GK} = \infty$; method 1 (linear voltage rise)		1000
P_{GM}	$T_{VJ} = 125^\circ\text{C}$ $I_T = I_{TAVM}$	$t_p = 30 \mu\text{s}$ $t_p = 300 \mu\text{s}$	10 5
P_{GAVM}			0.5
V_{RGM}			10
T_{VJ}		-40...+150	°C
T_{VJM}		150	°C
T_{stg}		-40...+125	°C
V_{ISOL}	50/60 Hz, RMS $I_{ISOL} \leq 1 \text{ mA}$	$t = 1 \text{ min}$ $t = 1 \text{ s}$	2500 3000
M_d	Mounting torque (M4)	1.5...2.0/14...18 Nm/lb.in.	
Weight	typ.	18	g

Data according to IEC 60747 and to a single thyristor/diode unless otherwise stated.
IXYS reserves the right to change limits, test conditions and dimensions.

$$I_{RMS} = 112 \text{ A}$$

$$V_{RRM} = 800-1400 \text{ V}$$

Features

- Thyristor controller for AC (circuit W1C acc. to IEC) for mains frequency
- Isolation voltage 3000 V~
- Planar glass passivated chips
- Low forward voltage drop
- Lead suitable for PC board solering

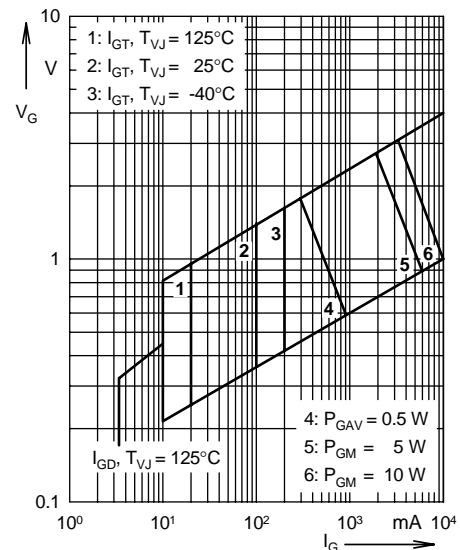
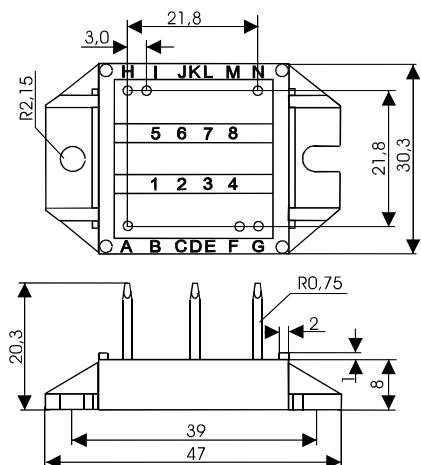
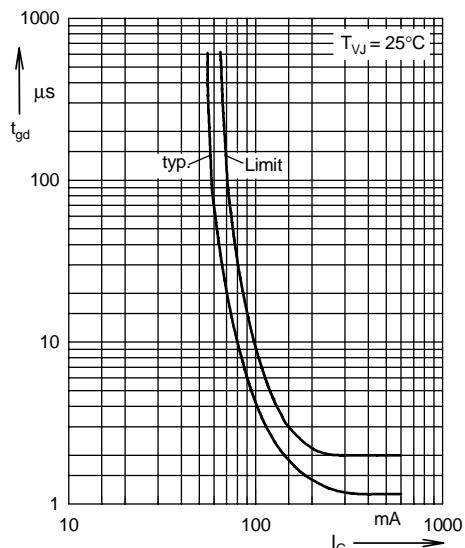
Applications

- Switching and control of single and three phase AC circuits
- Light and temperature control
- Softstart AC motor controller
- Solid state switches

Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling
- High power density
- Small and light weight

Symbol	Conditions	Characteristic Values			
I_D, I_R	$T_{VJ} = 125^\circ C; V_R = V_{RRM}; V_D = V_{DRM}$	≤	5	mA	
V_T	$I_T = 150 A; T_{VJ} = 25^\circ C$	≤	1.57	V	
V_{TO}	For power-loss calculations only	0.85		V	
r_T		5.6		$m\Omega$	
V_{GT}	$V_D = 6 V$	$T_{VJ} = 25^\circ C$	≤	1.5	V
		$T_{VJ} = -40^\circ C$	≤	1.9	V
I_{GT}	$V_D = 6 V$	$T_{VJ} = 25^\circ C$	≤	100	mA
		$T_{VJ} = -40^\circ C$	≤	200	mA
V_{GD}	$T_{VJ} = 125^\circ C; V_D = \frac{2}{3} V_{DRM}$	≤	0.2	V	
I_{GD}		≤	1	mA	
I_L	$T_{VJ} = 25^\circ C; t_p = 10 \mu s$	≤	200	mA	
	$I_G = 0.45 A; di_G/dt = 0.45 A/\mu s$				
I_H	$T_{VJ} = 25^\circ C; V_D = 6 V; R_{GK} = \infty$	≤	100	mA	
t_{gd}	$T_{VJ} = 25^\circ C; V_D = \frac{1}{2} V_{DRM}$	≤	2	μs	
	$I_G = 0.45 A; di_G/dt = 0.45 A/\mu s$				
R_{thJC}	per thyristor; DC	0.8		K/W	
	per module	0.4		K/W	
R_{thCH}	per thyristor; sine 180° el	typ.	0.12	K/W	
	per module	typ.	0.06	K/W	
d_s	Creeping distance on surface	11.2		mm	
d_a	Creepage distance in air	17.0		mm	
a	Max. allowable acceleration	50		m/s^2	

Dimensions in mm (1 mm = 0.0394")

Fig. 1 Gate trigger characteristics

Fig. 2 Gate trigger delay time